NSN 5961-01-358-0219

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-358-0219 **Inclosure Material:** Plastic **Overall Length:** 0.3125 inches **Overall Height:** 0.170 inches **Overall Width:** 0.196 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 0.80 amperes drain current **Power Rating Per Characteristic:** 1.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 4 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No